

SNVS741F - FEBRUARY 2000 - REVISED APRIL 2013

# LM185/LM285/LM385 Adjustable Micropower Voltage References

Check for Samples: LM185-ADJ, LM285-ADJ, LM385-ADJ

#### **FEATURES**

- Adjustable from 1.24V to 5.30V
- Operating Current of 10µA to 20mA
- 1% and 2% Initial Tolerance
- 1Ω Dynamic Impedance
- **Low Temperature Coefficient**

#### **DESCRIPTION**

The LM185/LM285/LM385 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a 10µA to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185 is rated for operation over a -55°C to 125°C temperature range, while the LM285 is rated -40°C to 85°C and the LM385 0°C to 70°C. The LM185 is available in a hermetic TO package and a LCCC package, while the LM285/LM385 are available in a low-cost TO-92 package, as well as SOIC.

#### **Connection Diagram**



Figure 1. TO-92 Package **Bottom View** 

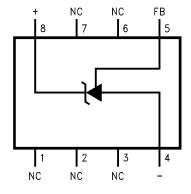


Figure 3. SOIC Package **Top View** 



Figure 2. TO Package **Bottom View** 

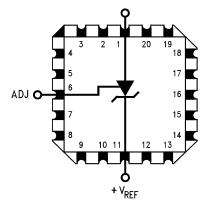
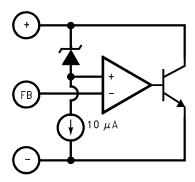


Figure 4. 20-LCCC **Top View** 

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### **Block Diagram**



## **Typical Applications**

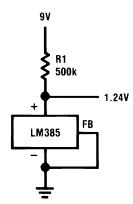


Figure 5. 1.2V Reference

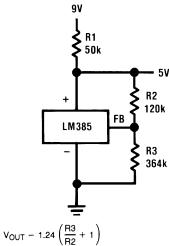


Figure 6. 5.0V Reference



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



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# Absolute Maximum Ratings (1)(2)(3)

Reverse Current	30mA							
Forward Current	10mA							
Operating Temperature Range (4)								
LM185 Series	−55°C to 125°C							
LM285 Series	-40°C to 85°C							
LM385 Series	0°C to 70°C							
ESD Susceptibility (5)	2kV							
Storage Temperature	−55°C to 150°C							
Soldering Information								
TO-92 Package (10 sec.)	260°C							
TO Package (10 sec.)	300°C							
SOIC Package								
Vapor Phase (60 sec.)	215°C							
Infrared (15 sec.)	220°C							
See An-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.								

<sup>(1)</sup> Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed.

- (2) Refer to RETS185H for military specifications.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (4) For elevated temperature operation, see Table 1 and Thermal Characteristics.
- (5) The human body model is a 100 pF capacitor discharged through a 1.5 k $\Omega$  resistor into each pin.

Table 1. T<sub>J(max)</sub> for Elevated Temperature Operation

DEVICE	T <sub>J(max)</sub> (°C)
LM185	150
LM285	125
LM385	100

#### **Thermal Characteristics**

Over operating free-air temperature range (unless otherwise noted)

Thermal Resistance	TO-92	TO-46	SOIC	
O (lunction to Ambient)	180°C/W (0.4" leads)	440°C/W	46F9CAN	
θ <sub>JA</sub> (Junction to Ambient)	170°C/W (0.125" leads)	440 C/VV	165°C/W	
θ <sub>JC</sub> (Junction to Case)	N/A	80°C/W	N/A	

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#### Electrical Characteristics(1)

			LM185, LM285 LM385												
Parameter	Condit	Conditions		Conditions		LM18 LM1 LM28	85BX, 85BY 85B, 85BX, 85BY	LM	285	Тур		35BX, 85BY	LM	385	Units (Limit)
				Tested Limit (2)	Design Limit	Tested Limit	Design Limit		Tested Limit	Design Limit	Tested Limit	Design Limit (3)			
Reference Voltage			1.240	1.252 1.255		1.265	1.270	1.240	1.252	1.255	1.265	1.270	V (max)		
				1.228 <b>1.215</b>		1.215	1.205		1.228	1.215	1.215	1.205	V (min)		
Reference	$I_{MIN} < I_R < 1mA$ $1mA < I_R < 20mA$		0.2	1	1.5	1	1.5	0.2	1	1.5	1	1.5	mV		
Voltage Change with Current			4	10	20	10	20	5	15	25	15	25	(max)		
Dynamic Output	$I_R = 100 \mu A$ ,	f = 100Hz													
Impedance	$I_{AC} = 0.1 I_{R}$	$V_{OUT} = V_{REF}$	0.3					0.4					Ω		
		V <sub>OUT</sub> = 5.3V	0.7					1							
Reference Voltage Change with Output Voltage	Ι <sub>R</sub> = 100μΑ		1	3	6	3	6	2	5	10	5	10	mV (max)		
Feedback Current			13	20	25	20	25	16	30	35	30	35	nA (max)		
Minimum Operating Current (see curve)	$V_{OUT} = V_{REF}$ $V_{OUT} = 5.3V$		6 30	9 45	10 50	9 45	10 50	7 35	11 55	13 60	11 55	13 60	μA (max)		
Output Wideband	I <sub>R</sub> = 100μA, < 10kHz	10Hz < f											$\mu V_{rms}$		
Noise	$V_{OUT} = V_{REF}$		50					50							
	$V_{OUT} = 5.3V$	1	170					170							
Average Temperature Coefficient	I <sub>R</sub> = 100μA	X Suffix Y Suffix All		30 50	150		150		30 50	150		150	ppm/°c (max)		
Long Term Stability	Others $I_R = 100\mu\text{A}, T = 1000$ Hr, $T_A = 25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$		20					20					ppm		

<sup>(1)</sup> Parameters identified with **boldface type** apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25$ °C. Unless otherwise specified, all parameters apply for  $V_{REF} < V_{OUT} < 5.3$ V.

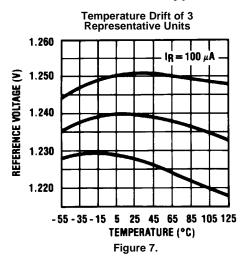
<sup>(2)</sup> Production tested.

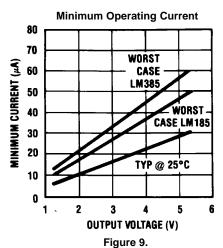
<sup>(3)</sup> Not production tested. These limits are not to be used to calculate average outgoing quality levels.

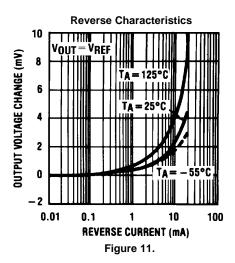
<sup>(4)</sup> The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures from T<sub>MIN</sub> to T<sub>MAX</sub>, divided by T<sub>MAX</sub> – T<sub>MIN</sub>. The measured temperatures are –55, –40, 0, 25, 70, 85, 125°C.

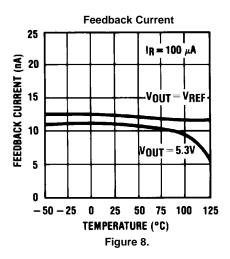


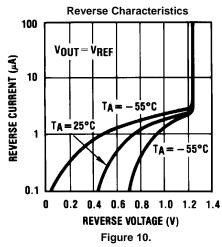
### **Typical Performance Characteristics**

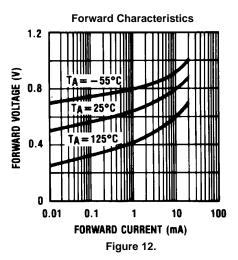






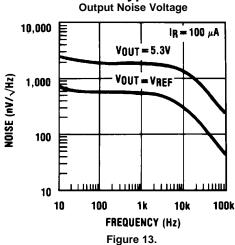








### Typical Performance Characteristics (continued)



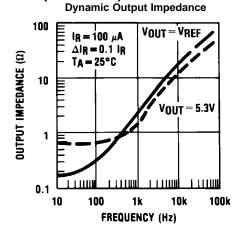
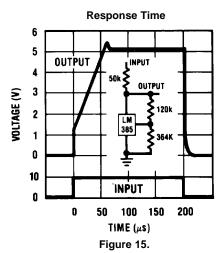
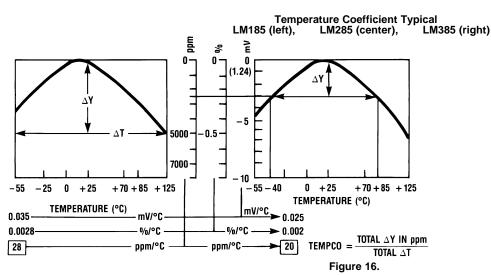
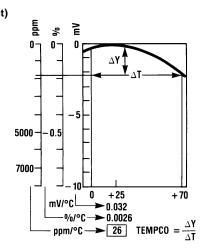


Figure 14.









#### **TYPICAL APPLICATIONS**

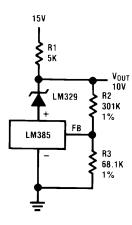


Figure 17. Precision 10V Reference

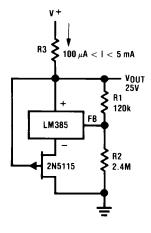


Figure 19. 25V Low Current Shunt Regulator

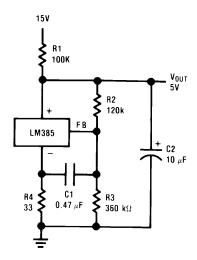


Figure 18. Low AC Noise Reference

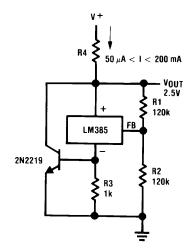
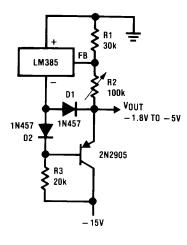


Figure 20. 200 mA Shunt Regulator





5.1V TO 16V VIN > HEAT SINK  $\begin{array}{l} \mbox{Iq} = 70~\mu \mbox{ A} \\ \mbox{0} < \mbox{I}_{\mbox{OUT}} < 50 \mbox{ mA} \end{array}$ 22k 2N2905 R7 332k 1°′  $R2 \leq R3 \leq 1M \leq 1$ R4 3k 1 M 10K LM385 **C**1 C2 R5  $0.1 \mu F$ 500 μF 2N3904 R8 1 M 10k 2N3904 1% **≯** R6 22k

Figure 21. Series-Shunt 20 mA Regulator

Figure 22. High Efficiency Low Power Regulator

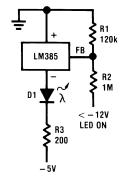


Figure 23. Voltage Level Detector

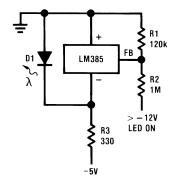


Figure 24. Voltage Level Detector

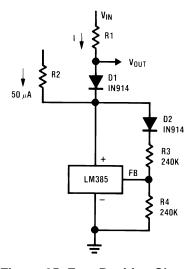


Figure 25. Fast Positive Clamp  $2.4V + \Delta V_{D1}$ 

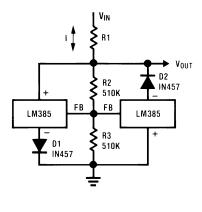


Figure 26. Bidirectional Clamp ±2.4V



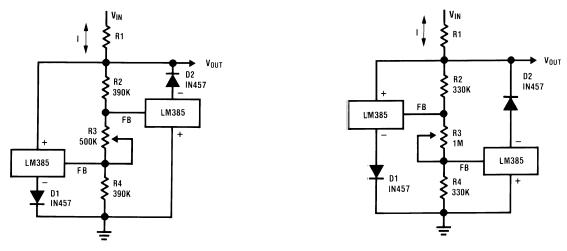


Figure 27. Bidirectional Adjustable Clamp ±1.8V to ±2.4V

Figure 28. Bidirectional Adjustable Clamp ±2.4V to ±6V

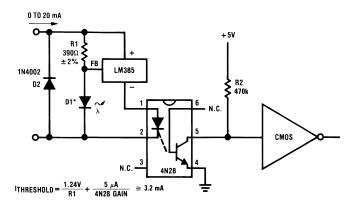


Figure 29. Simple Floating Current Detector

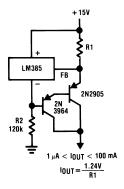
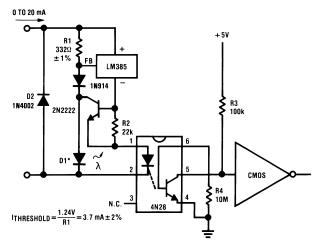


Figure 30. Current Source





\*D1 can be any LED,  $V_F$ =1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if  $I_{THRESHOLD}$  falls below the threshold current, except with I=O.

Figure 31. Precision Floating Current Detector

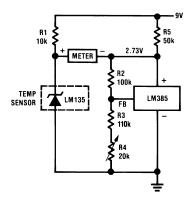


Figure 32. Centigrade Thermometer, 10mV/°C

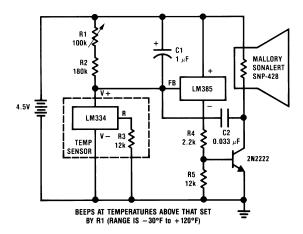
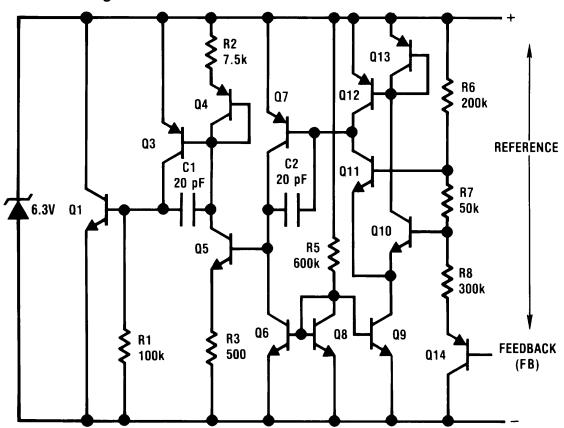


Figure 33. Freezer Alarm



# **Schematic Diagram**





## **REVISION HISTORY**

Cr	Changes from Revision E (April 2013) to Revision F						
•	Changed layout of National Data Sheet to TI format		11				

4-Aug-2022 www.ti.com

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	<b>Device Marking</b> (4/5)	Samples
LM185BH	ACTIVE	ТО	NDV	3	1000	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	( LM185BH, LM185BH )	Samples
LM185BH/NOPB	ACTIVE	ТО	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	( LM185BH, LM185BH )	Samples
LM285BXZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	-40 to 85	LM285 BXZ	Samples
LM285BYM/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM285 BYM	Samples
LM285BYMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM285 BYM	Samples
LM285BYZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	-40 to 85	LM285 BYZ	Samples
LM285M/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M	Samples
LM285MX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M	Samples
LM285Z/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	-40 to 85	LM285 Z	Samples
LM385BM/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM	Samples
LM385BMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM	Samples
LM385BXZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM385 BXZ	Samples
LM385BYZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM385 BYZ	Samples
LM385BZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM385 BZ	Samples
LM385M	NRND	SOIC	D	8	95	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	0 to 70	LM385 M	
LM385M/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM385 M	Samples

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Orderable Device	Status	Package Type		Pins	_	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
LM385MX	NRND	SOIC	D	8	2500	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	0 to 70	LM385 M	
LM385MX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM385 M	Samples
LM385Z/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM385 Z	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



# **PACKAGE OPTION ADDENDUM**

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PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All diffiensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM285BYMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM285MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385MX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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\*All dimensions are nominal

7 til dilliciololio are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM285BYMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM285MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385MX	SOIC	D	8	2500	367.0	367.0	35.0
LM385MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

# PACKAGE MATERIALS INFORMATION

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM285BYM/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM285M/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385BM/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385M	D	SOIC	8	95	495	8	4064	3.05
LM385M	D	SOIC	8	95	495	8	4064	3.05
LM385M/NOPB	D	SOIC	8	95	495	8	4064	3.05



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040001-2/F



TO-92 - 5.34 mm max height

TO-92



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. Lead dimensions are not controlled within this area.4. Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

  - a. Straight lead option available in bulk pack only.
     b. Formed lead option available in tape and reel or ammo pack.
  - c. Specific products can be offered in limited combinations of shipping medium and lead options.
  - d. Consult product folder for more information on available options.















#### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC registration TO-46.





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